

## General Description

The AO4413 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , and ultra-low low gate charge with a 25V gate rating. This device is suitable for use as a load switch or in PWM applications.

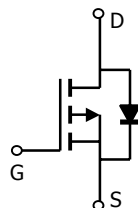
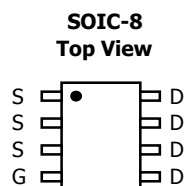
## Features

$$V_{DS} (V) = -30V$$

$$I_D = -15A$$

$$R_{DS(ON)} < 7m\Omega (V_{GS} = -20V)$$

$$R_{DS(ON)} < 8.5m\Omega (V_{GS} = -10V)$$



### Absolute Maximum Ratings $T_A=25^\circ C$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 25$	V
Continuous Drain Current <sup>A</sup>	$I_D$	$T_A=25^\circ C$	-15
		$T_A=70^\circ C$	-12.8
Pulsed Drain Current <sup>B</sup>	$I_{DM}$	-80	A
Power Dissipation <sup>A</sup>	$P_D$	$T_A=25^\circ C$	3
		$T_A=70^\circ C$	2.1
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	$^\circ C$

### Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient <sup>A</sup>	$R_{\theta JA}$	$t \leq 10s$	26	$^\circ C/W$
Maximum Junction-to-Ambient <sup>A</sup>		Steady-State	50	$^\circ C/W$
Maximum Junction-to-Lead <sup>C</sup>	$R_{\theta JL}$	14	24	$^\circ C/W$

Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>STATIC PARAMETERS</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$I_D=-250\mu\text{A}$ , $V_{GS}=0\text{V}$	-30			V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=-24\text{V}$ , $V_{GS}=0\text{V}$ $T_J=55^\circ\text{C}$			-1 -5	$\mu\text{A}$
$I_{GSS}$	Gate-Body leakage current	$V_{DS}=0\text{V}$ , $V_{GS}=\pm 25\text{V}$			$\pm 100$	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D=-250\mu\text{A}$	-1.5	-2.6	-3.5	V
$I_{D(ON)}$	On state drain current	$V_{GS}=-10\text{V}$ , $V_{DS}=-5\text{V}$	60			A
$R_{DS(ON)}$	Static Drain-Source On-Resistance	$V_{GS}=-20\text{V}$ , $I_D=-15\text{A}$ $T_J=125^\circ\text{C}$		5.8 7.2	7 8.7	$\text{m}\Omega$
		$V_{GS}=-10\text{V}$ , $I_D=-15\text{A}$		7.2	8.5	$\text{m}\Omega$
		$V_{GS}=-6\text{V}$ , $I_D=-10\text{A}$		10.4		$\text{m}\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS}=-5\text{V}$ , $I_D=-15\text{A}$		38		S
$V_{SD}$	Diode Forward Voltage	$I_S=-1\text{A}$ , $V_{GS}=0\text{V}$		-0.72	-1	V
$I_S$	Maximum Body-Diode Continuous Current				-4.2	A
<b>DYNAMIC PARAMETERS</b>						
$C_{iss}$	Input Capacitance	$V_{GS}=0\text{V}$ , $V_{DS}=-15\text{V}$ , $f=1\text{MHz}$		5034		pF
$C_{oss}$	Output Capacitance			1076		pF
$C_{rSS}$	Reverse Transfer Capacitance			829		pF
$R_g$	Gate resistance	$V_{GS}=0\text{V}$ , $V_{DS}=0\text{V}$ , $f=1\text{MHz}$		2.5		$\Omega$
<b>SWITCHING PARAMETERS</b>						
$Q_g$	Total Gate Charge	$V_{GS}=-10\text{V}$ , $V_{DS}=-15\text{V}$ , $I_D=-15\text{A}$		78		nC
$Q_{gs}$	Gate Source Charge			15.2		nC
$Q_{gd}$	Gate Drain Charge			23.6		nC
$t_{D(on)}$	Turn-On Delay Time	$V_{GS}=-10\text{V}$ , $V_{DS}=-15\text{V}$ , $R_L=1.0\Omega$ , $R_{GEN}=3\Omega$		17.5		ns
$t_r$	Turn-On Rise Time			19.5		ns
$t_{D(off)}$	Turn-Off Delay Time			49		ns
$t_f$	Turn-Off Fall Time			30.5		ns
$t_{rr}$	Body Diode Reverse Recovery Time	$I_F=-15\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$		43		ns
$Q_{rr}$	Body Diode Reverse Recovery Charge	$I_F=-15\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$		38		nC

A: The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any a given application depends on the user's specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C: The  $R_{\theta JA}$  is the sum of the thermal impedance from junction to lead  $R_{\theta JL}$  and lead to ambient.

D: The static characteristics in Figures 1 to 6, 12, 14 are obtained using 80 $\mu\text{s}$  pulses, duty cycle 0.5% max.

E: These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The SOA curve provides a single pulse rating.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

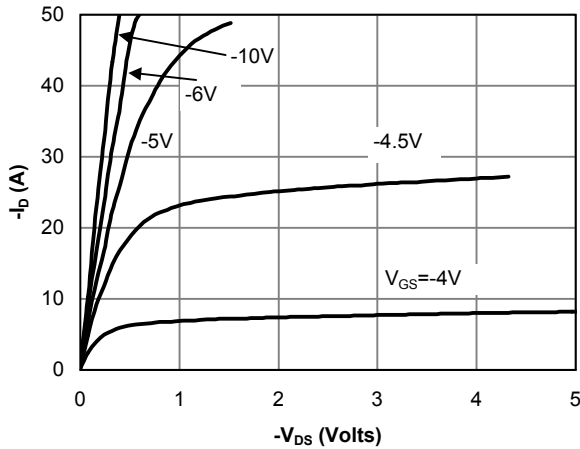


Fig 1: On-Region Characteristics

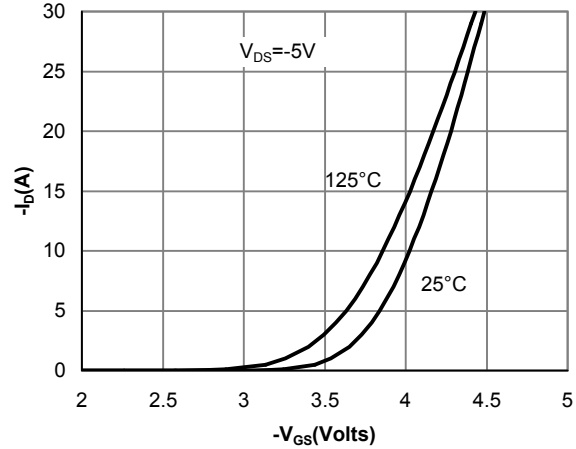


Figure 2: Transfer Characteristics

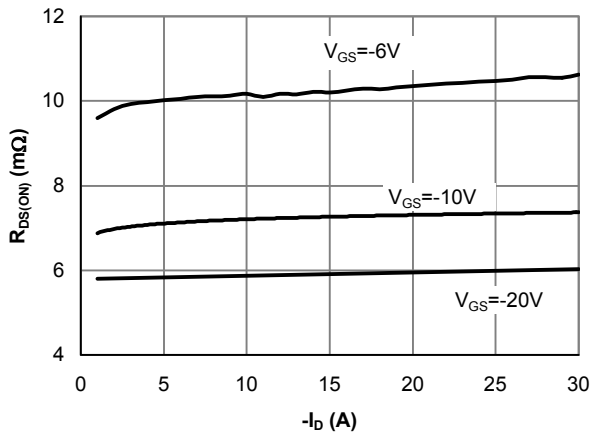


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

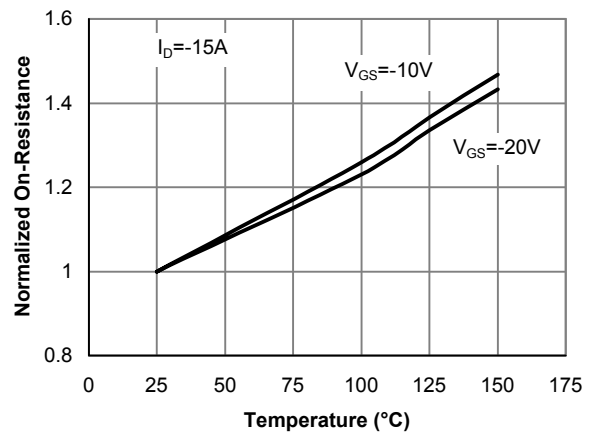


Figure 4: On-Resistance vs. Junction Temperature

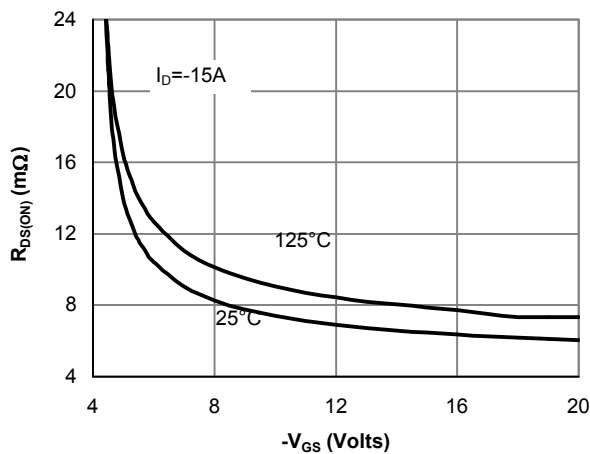


Figure 5: On-Resistance vs. Gate-Source Voltage

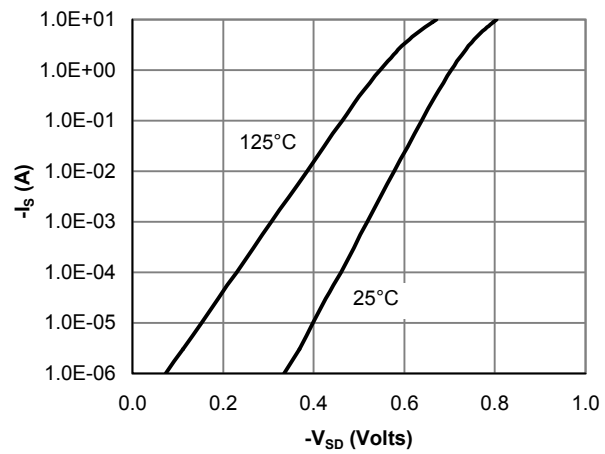


Figure 6: Body-Diode Characteristics

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

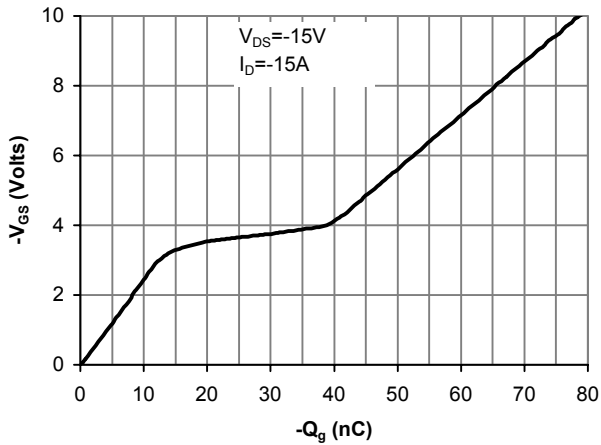


Figure 7: Gate-Charge Characteristics

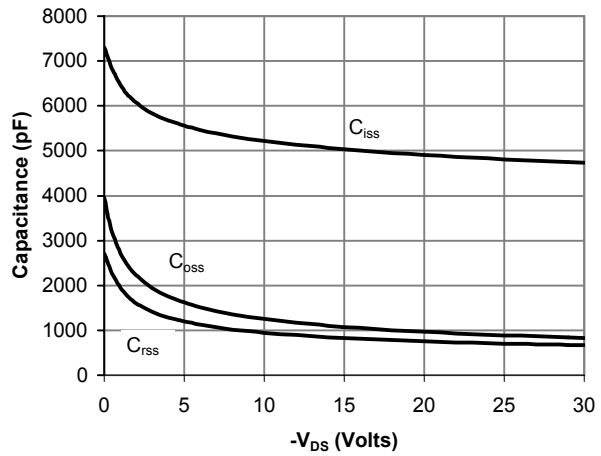


Figure 8: Capacitance Characteristics

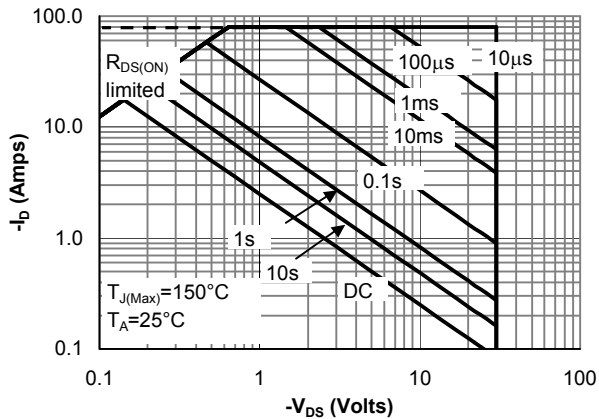


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

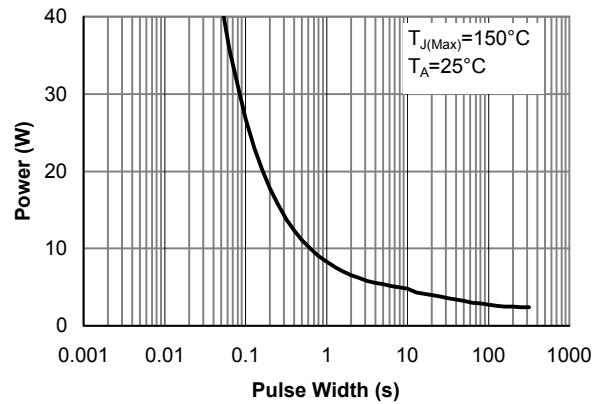


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

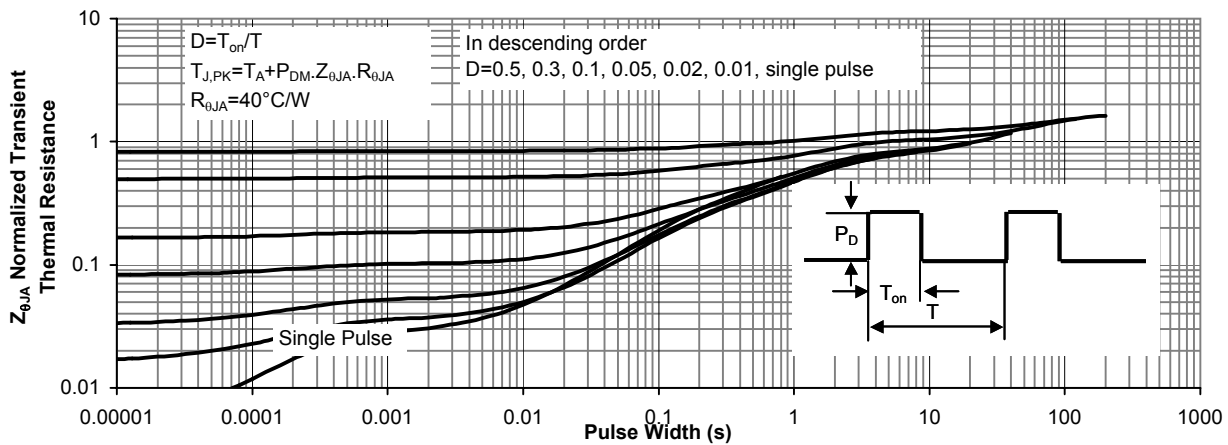
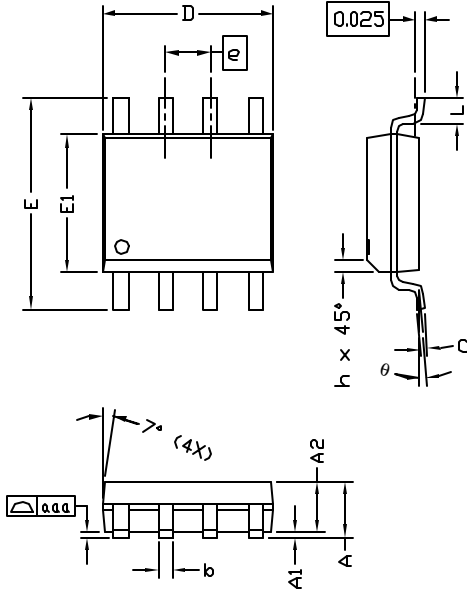


Figure 11: Normalized Maximum Transient Thermal Impedance



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.45	1.50	1.55	0.057	0.059	0.061
A1	0.00	—	0.10	0.000	—	0.004
A2	—	1.45	—	—	0.057	—
b	0.33	—	0.51	0.013	—	0.020
c	0.19	—	0.25	0.007	—	0.010
D	4.80	—	5.00	0.189	—	0.197
E1	3.80	—	4.00	0.150	—	0.157
e	1.27 BSC			0.050 BSC		
E	5.80	—	6.20	0.228	—	0.244
h	0.25	—	0.50	0.010	—	0.020
L	0.40	—	1.27	0.016	—	0.050
aaa	—	—	0.10	—	—	0.004
θ	0°	—	8°	0°	—	8°

NOTE:  
 1. LEAD FINISH: 150 MICROINCHES ( 3.8 um) MIN.  
 THICKNESS OF Tin/Lead (SOLDER) PLATED ON LEAD  
 2. TOLERANCE ±0.10 mm (4 mil) UNLESS OTHERWISE SPECIFIED  
 3. COPLANARITY : 0.10 mm  
 4. DIMENSION L IS MEASURED IN GAGE PLANE

### PACKAGE MARKING DESCRIPTION

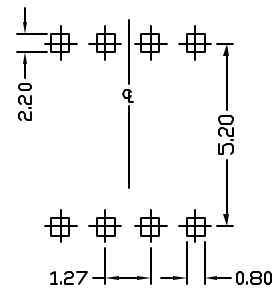


NOTE:  
 LOGO - AOS LOGO  
 4413 - PART NUMBER CODE.  
 F - FAB LOCATION  
 A - ASSEMBLY LOCATION  
 Y - YEAR CODE  
 W - WEEK CODE.  
 LC - ASSEMBLY LOT CODE

### SOP-8 PART NO. CODE

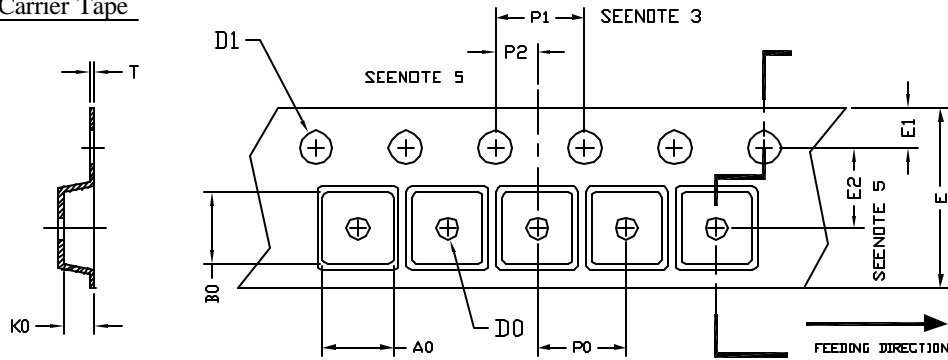
PART NO.	CODE
AO4413	4413

### RECOMMENDED LAND PATTERN



UNIT: mm

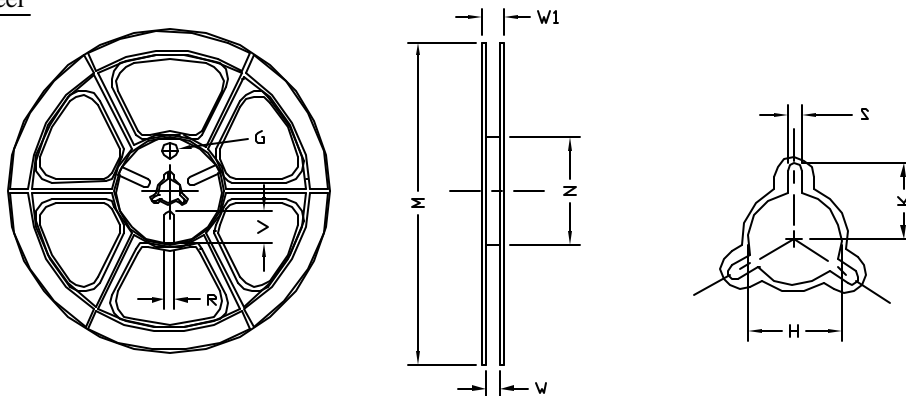
## SO-8 Carrier Tape



UNIT: MM

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SO-8 (12 mm)	6.40 ±0.10	5.20 ±0.10	2.10 ±0.10	1.60 ±0.10	1.30 ±0.10	12.00 ±0.30	1.75 ±0.10	5.50 ±0.05	8.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.25 ±0.05

## SO-8 Reel



UNIT: MM

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
12 mm	φ330	φ330.00 ±0.50	φ97.00 ±0.10	13.00 ±0.30	17.40 ±1.00	φ13.00 +0.50 -0.20	10.60	2.00 ±0.50	---	---	---

## SO-8 Tape

Leader / Trailer  
& Orientation

